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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/588,064	08/01/2006	Kiyoshi Kato	0756-7772	4335
31780 7590 10/30/2008 ERIC ROBINSON			EXAMINER	
PMB 955	DANIZ CT	WEINBERG, MICHAEL J		
21010 SOUTHBANK ST. POTOMAC FALLS, VA 20165			ART UNIT	PAPER NUMBER
			2827	
			MAIL DATE	DELIVERY MODE
			10/30/2008	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)			
	10/588,064	KATO, KIYOSHI			
Office Action Summary	Examiner	Art Unit			
	Michael J. Weinberg	2827			
The MAILING DATE of this communication Period for Reply	appears on the cover sheet wit	h the correspondence address			
A SHORTENED STATUTORY PERIOD FOR RE WHICHEVER IS LONGER, FROM THE MAILING  - Extensions of time may be available under the provisions of 37 CFF after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory per  - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the material patent term adjustment. See 37 CFR 1.704(b).	E DATE OF THIS COMMUNIC R 1.136(a). In no event, however, may a re- riod will apply and will expire SIX (6) MONT atute, cause the application to become ABA	ATION. ply be timely filed  HS from the mailing date of this communication. ANDONED (35 U.S.C. § 133).			
Status					
1) ☐ Responsive to communication(s) filed on <u>0</u> :  2a) ☐ This action is <b>FINAL</b> . 2b) ☐ T  3) ☐ Since this application is in condition for allow closed in accordance with the practice under	his action is non-final.  wance except for formal matte	-			
Disposition of Claims					
4)  Claim(s) 1-17 is/are pending in the application 4a) Of the above claim(s) 2,4,6,8,10 and 12  5)  Claim(s) is/are allowed.  6)  Claim(s) 1, 3, 5, 7, 9, 11, and 13-17 is/are objected to restriction and are subject to restriction and are subjected to by the Exame 10)  The drawing(s) filed on 01 August 2006 is/a Applicant may not request that any objection to the Replacement drawing sheet(s) including the contraction and the subject of the subj	rejected. cted to. d/or election requirement.  niner. re: a)⊠ accepted or b)□ obj	ected to by the Examiner. se. See 37 CFR 1.85(a).			
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.					
Priority under 35 U.S.C. § 119					
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>					
Attachment(s)  1) ☑ Notice of References Cited (PTO-892)  2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) ☑ Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date See Continuation Sheet.	Paper No(s) 5) Notice of Int	ummary (PTO-413) /Mail Date formal Patent Application tated portions of US 7,188,282.			

 $Continuation \ of \ Attachment(s)\ 3).\ Information \ Disclosure \ Statement(s)\ (PTO/SB/08),\ Paper\ No(s)/Mail\ Date : 10/24/2007,\ 7/25/2007,\ and\ 8/1/2006.$ 

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## **DETAILED ACTION**

#### Information Disclosure Statement

1. The information disclosure statements (IDS) submitted on 10/24/2007, 7/25/2007, and 8/1/2006 were considered by the examiner.

#### Election/Restrictions

2. Applicant's election without traverse of the species of claims 1, 3, 5, 7, 9, 11, and 13-17 in the reply filed on 10/1/2008 is acknowledged. Claims 2, 4, 6, 8, 10, and 12 are withdrawn from consideration.

### Claim Objections

3. Claims 1, 3, 5, 7, 9, 11, and 13-17 are objected to because of the following informalities:

Because of awkward language, Applicants are requested to proofread the claims to ensure that the translation from Japanese is correct.

# Claim Rejections - 35 USC § 102

- 4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:
  - (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 5. Claims 1, 3, 5, 7, and 13-17 are rejected under 35 U.S.C. 102(e) as being anticipated by Walmsley (US Patent 7,188,282, originally filed 12/2/2003).

Because of the length of the reference (774 pages), attached is a scan of annotated relevant portions for the convenience of Applicant. Other passages may apply as well, however.

With regard to independent claims **1**, **3**, **5**, **and 7**, Walmsley discloses a nonvolatile (flash) memory comprising a pair of memory elements (see abstract and col. 804 and 825) as a unit that can transit only from a first state to a second state (see col. 825) that are different in electric characteristics (threshold voltage or charge) by applying at least a voltage or a current (As is inherent for flash memory, charge is deposited in the form of voltage and current.),

wherein a memory cell is formed that stores 1-bit data by using two states that one memory element is in the first state (bit) and the other memory element is in the second state (inverse-bit). One bit data is stored using two bits (4 states).

With regard to **claim 13**, Walmsley discloses a nonvolatile memory of the above discussed claims wherein a unit for outputting a signal for determining if the memory cell stores data or not is provided. (See col. 805)

With regard to **claim 14**, Walmsley discloses that the memory element is a flash memory which has a floating gate. (See col. 651) Floating gates are known in the art to always be made of metal, so it is considered inherent that the charge accumulating layer comprises metal.

With regard to **claims 15-17**, Walmsley teaches an integrated circuit (IC) which may be used for identification (ID) data for the printer system which is inherently a card or tag.

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## Claim Rejections - 35 USC § 103

6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

7. **Claims 9 and 11** are rejected under 35 U.S.C. 103(a) as being unpatentable over Walmsley above in view of APA (admitted prior art, page 1 of the specification).

Walmsley discloses all the elements of the claim as discussed above, except he does not use a resistive memory programmed by a current. However, as is well known in the art and discussed in APA, magnetoresistive and phase change memories are resistive memories known to be programmed using current.

As is known, it would have been obvious to one of ordinary skill in the art to use either of these memories to replace the flash memory of Walmsley because programming these new memories is generally faster and takes less voltage.

#### Conclusion

8. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michael J. Weinberg whose telephone number is (571)272-6424. The examiner can normally be reached on M-F 9:00 am-5:30 pm.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 571-272-1852. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Michael J. Weinberg/ Examiner, Art Unit 2827

/Huan Hoang/ Primary Examiner, Art Unit 2827